

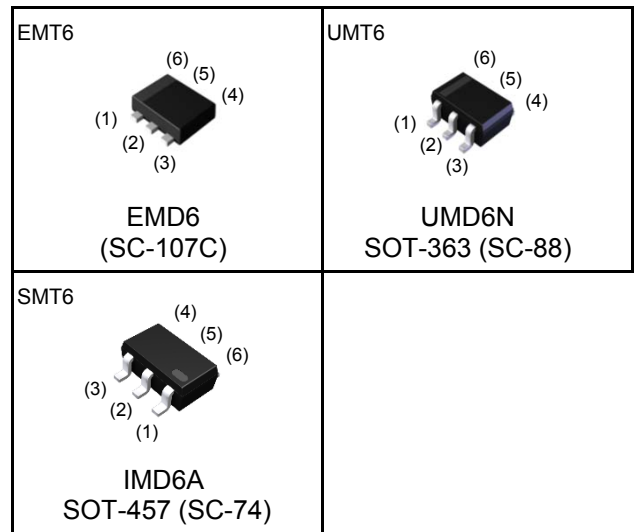
<For DTr1(NPN)>

Parameter	Value
V_{CEO}	50V
I_C	100mA
R_1	4.7k Ω

<For DTr2(PNP)>

Parameter	Value
V_{CEO}	-50V
I_C	-100mA
R_1	4.7k Ω

●Outline



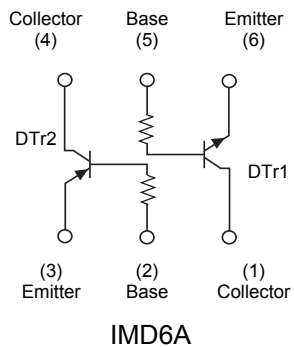
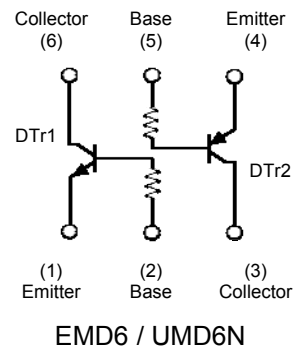
●Features

- 1) Both the DTC143T chip and DTA143T chip in one package.
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Lead Free/RoHS Compliant.

●Application

Inverter circuit, Interface circuit, Driver circuit

●Inner circuit



●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMD6	EMT6	1616	T2R	180	8	8,000	D6
UMD6N	UMT6	2021	TR	180	8	3,000	D6
IMD6A	SMT6	2928	T108	180	8	3,000	D6

●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	DTr1(NPN)	DTr2(PNP)	Unit
Collector-base voltage		V_{CBO}	50	-50	V
Collector-emitter voltage		V_{CEO}	50	-50	V
Emitter-base voltage		V_{EBO}	5	-5	V
Collector current		I_C	100	-100	mA
Collector Power dissipation	EMD6 / UMD6N	P_C^{*2}	150 (Total) ^{*3}		mW
	IMD6A		300 (Total) ^{*4}		mW
Junction temperature		T_j	150		°C
Range of storage temperature		T_{stg}	-55 to +150		°C

●Electrical characteristics (Ta = 25°C) <For DTr1(NPN)>

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	BV_{CBO}	$I_C = 50\mu A$	50	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = 1mA$	50	-	-	
Emitter-base breakdown voltage	BV_{EBO}	$I_E = 50\mu A$	5	-	-	
Collector cut-off current	I_{CBO}	$V_{CB} = 50V$	-	-	500	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 4V$	-	-	500	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C / I_B = 5mA / 0.25mA$	-	-	300	mV
DC current gain	h_{FE}	$V_{CE} = 5V, I_C = 1mA$	100	300	600	-
Input resistance	R_1	-	3.29	4.7	6.11	-
Transition frequency	f_T^{*1}	$V_{CE} = 10V, I_E = -5mA$ $f = 100MHz$	-	250	-	MHz

●Electrical characteristics (Ta = 25°C) <For DTr2(PNP)>

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	BV_{CBO}	$I_C = -50\mu A$	-50	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = -1mA$	-50	-	-	
Emitter-base breakdown voltage	BV_{EBO}	$I_E = -50\mu A$	-5	-	-	
Collector cut-off current	I_{CBO}	$V_{CB} = -50V$	-	-	-500	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -4V$	-	-	-500	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C / I_B = -5mA / -0.25mA$	-	-	-300	mV
DC current gain	h_{FE}	$V_{CE} = -5V, I_C = -1mA$	100	300	600	-
Input resistance	R_1	-	3.29	4.7	6.11	-
Transition frequency	f_T^{*1}	$V_{CE} = -10V, I_E = 5mA$ $f = 100MHz$	-	250	-	MHz

*1 Characteristics of built-in transistor

*2 Each terminal mounted on a reference footprint

*3 120mW per element must not be exceeded.

*4 200mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C) <For DTr1(NPN)>

Fig.1 Grounded emitter propagation characteristics

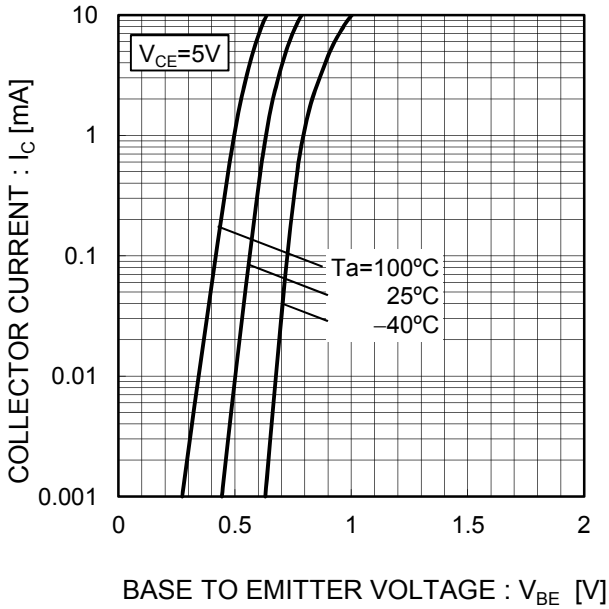


Fig.2 Grounded emitter output characteristics

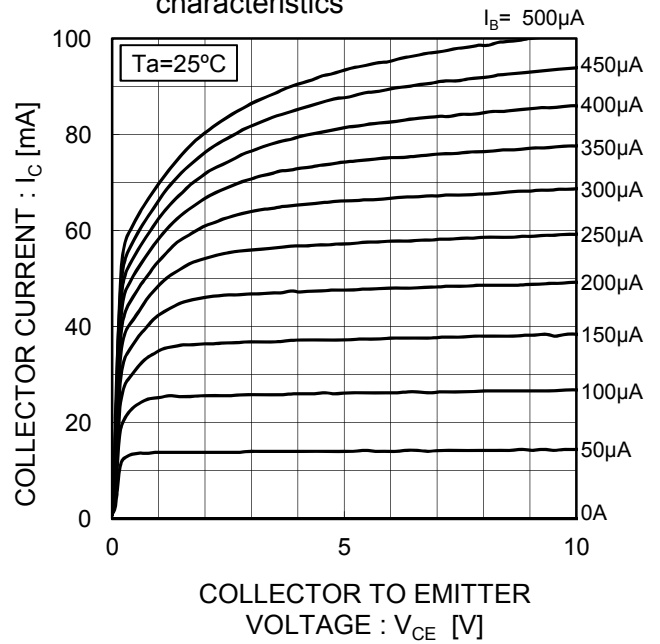


Fig.3 DC Current gain vs. Collector Current

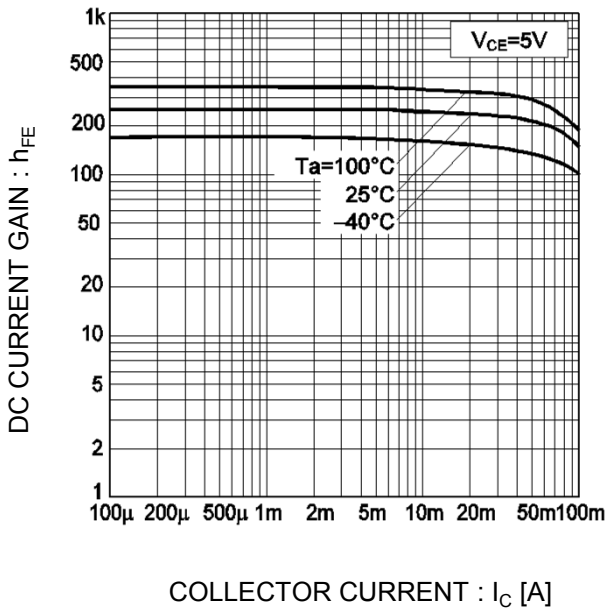
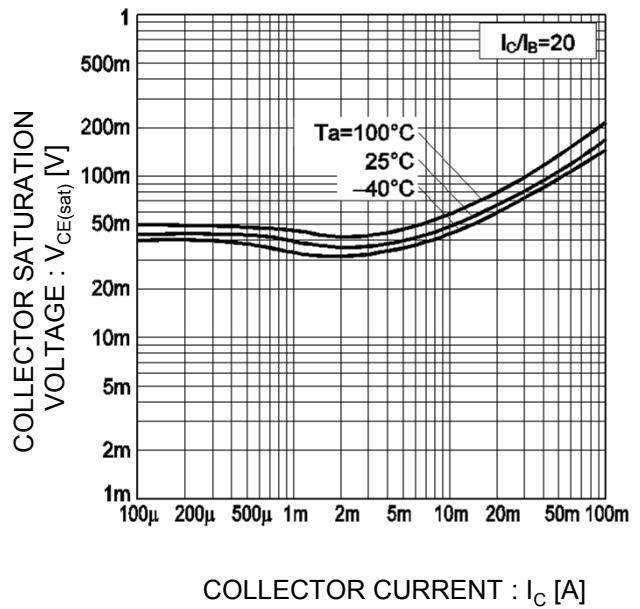


Fig.4 Collector-emitter saturation voltage vs. Collector Current



●Electrical characteristic curves(Ta = 25°C) <For DTr2(PNP)>

Fig.1 Grounded emitter propagation characteristics

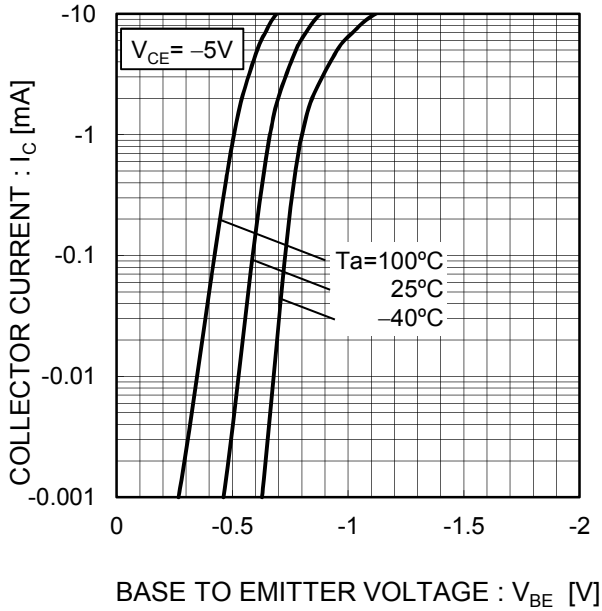


Fig.2 Grounded emitter output characteristics

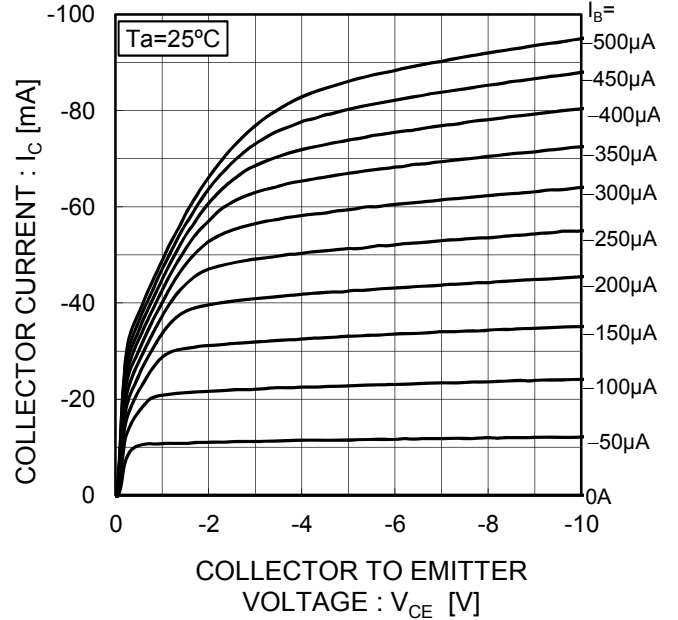


Fig.3 DC Current gain vs. Collector Current

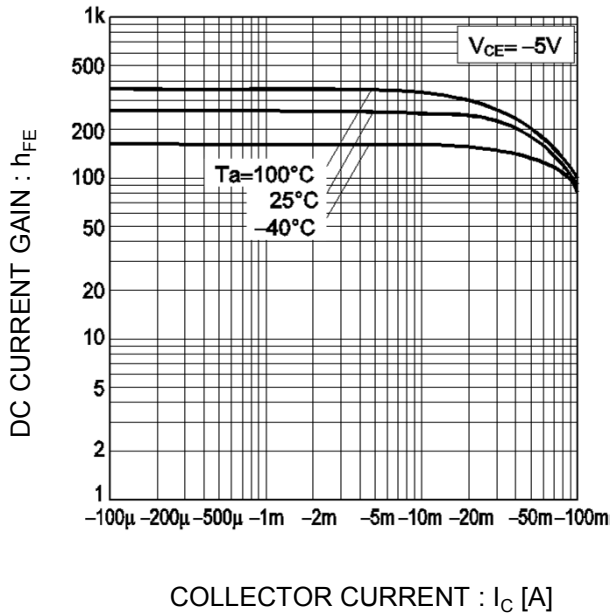
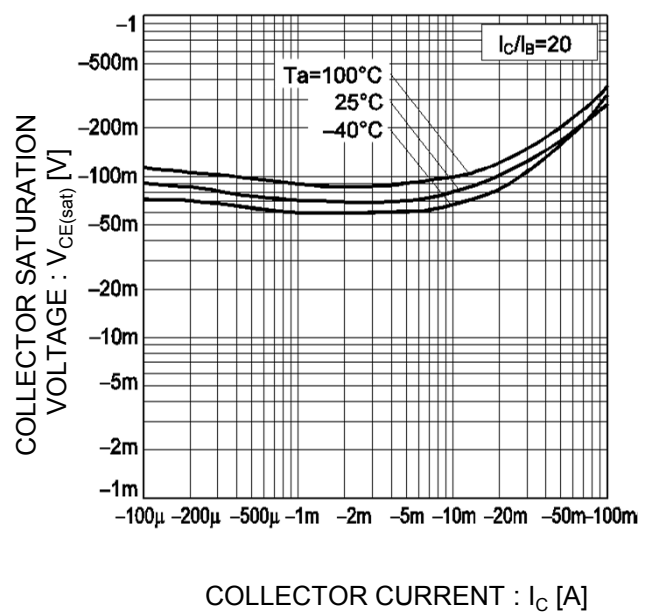
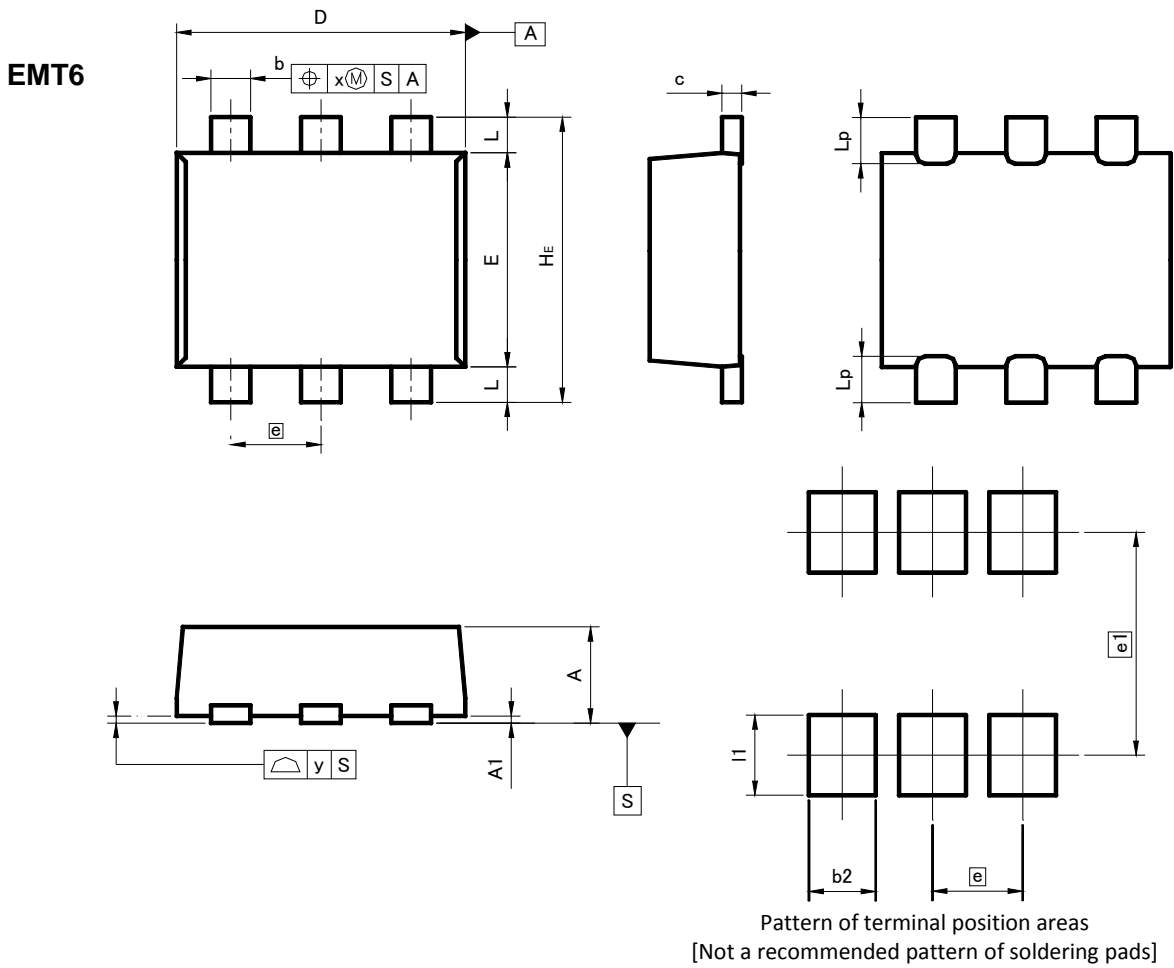


Fig.4 Collector-emitter saturation voltage vs. Collector Current



●Dimensions (Unit : mm)



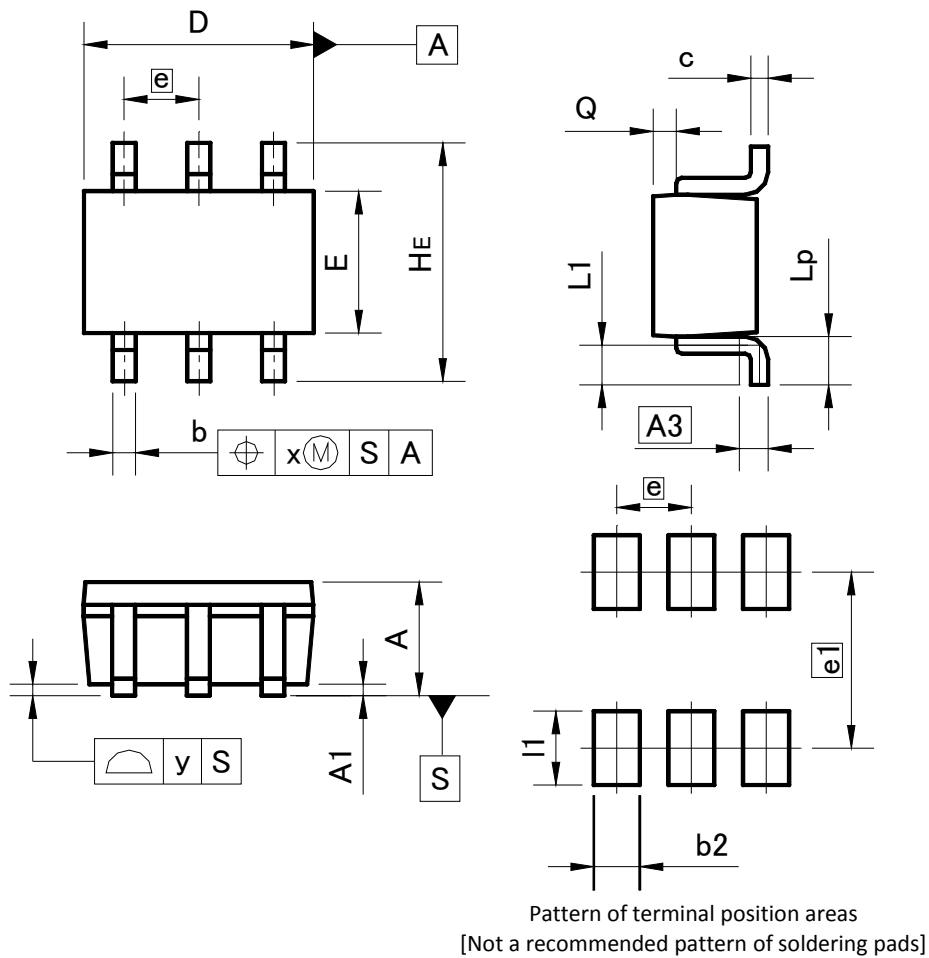
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
e1	1.25		0.049	
l1	-	0.45	-	0.018

Dimension in mm / inches

●Dimensions (Unit : mm)

UMT6



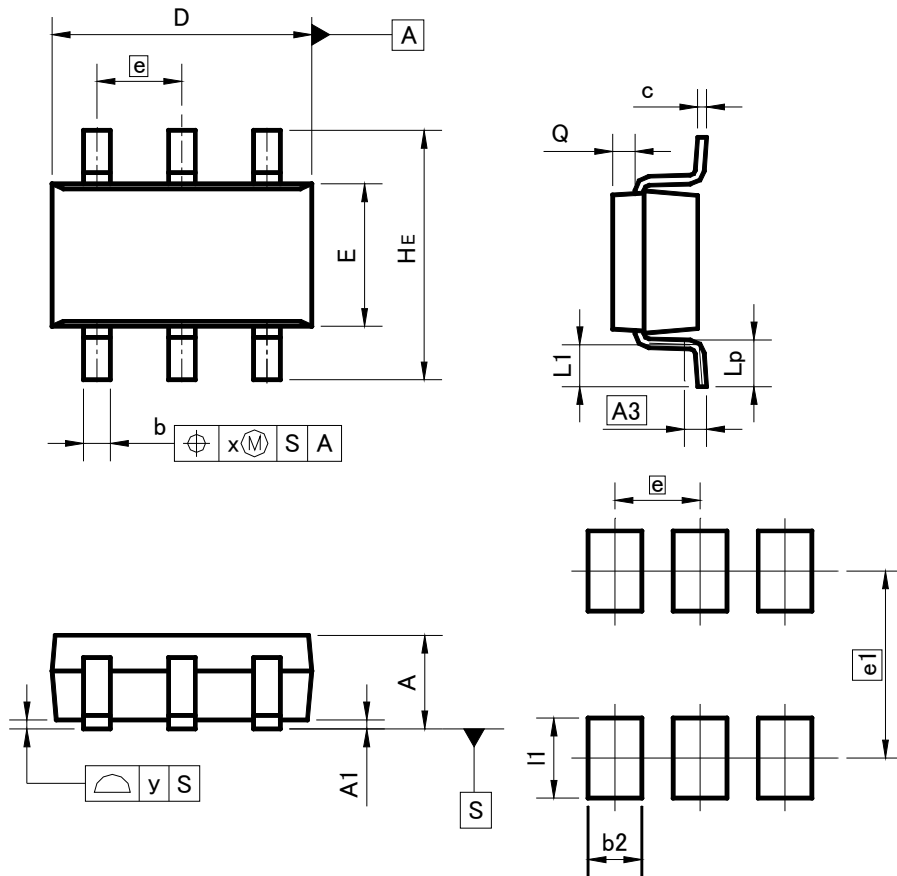
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.40	-	0.016
e1	1.55		0.061	
l1	-	0.65	-	0.026

Dimension in mm / inches

●Dimensions (Unit : mm)

SMT6



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.25	0.40	0.010	0.016
c	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.20	-	0.008
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.60	-	0.024
e1	2.10		0.083	
l1	-	0.90	-	0.035

Dimension in mm / inches

Notes

- 1) The information contained herein is subject to change without notice.
- 2) Before you use our Products, please contact our sales representative and verify the latest specifications :
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.
Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Products beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- 9) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrant that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting from non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

<http://www.rohm.com/contact/>



UMD6N - Web Page

[Distribution Inventory](#)

Part Number	UMD6N
Package	UMT6
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes